


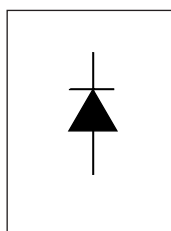
**INPUT RECTIFIER DIODE  
TO-220 FULLPAK**

**Description/Features**

The 20ETS..FP rectifier **SAFEIR** series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150°C junction temperature.

Typical applications are in input rectification and these products are designed to be used with International Rectifier Switches and Output Rectifiers which are available in identical package outlines. Fully isolated package ( $V_{INS} = 2500 V_{RMS}$ ).

UL E78996 approved 



$V_F < 1V @ 10A$
$I_{FSM} = 300A$
$V_{RRM} 800 \text{ to } 1600V$

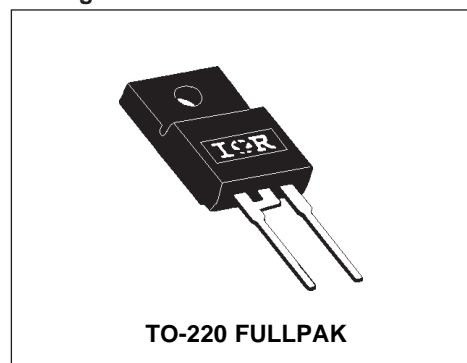
**Output Current in Typical Applications**

Applications	Single-phase Bridge	Three-phase Bridge	Units
Capacitive input filter $T_A = 55^\circ C, T_J = 125^\circ C,$ common heatsink of $1^\circ C/W$	18	22	A

**Major Ratings and Characteristics**

Characteristics	20ETS..FP	Units
$I_{F(AV)}$ Sinusoidal waveform	20	A
$V_{RRM}$	800 to 1600	V
$I_{FSM}$	300	A
$V_F @ 10A, T_J = 25^\circ C$	1.0	V
$T_J$	-40 to 150	$^\circ C$

**Package Outline**



## Voltage Ratings

Part Number	$V_{RRM}$ , maximum peak reverse voltage V	$V_{RSM}$ , maximum non repetitive peak reverse voltage V	$I_{RRM}$ 150°C mA
20ETS08FP	800	900	1
20ETS12FP	1200	1300	
20ETS16FP	1600	1700	

Provide terminal coating for voltages above 1200V

## Absolute Maximum Ratings

Parameters	20ETS..FP	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	20	A	@ $T_C=88^\circ\text{C}$ , 180° conduction half sine wave
$I_{FSM}$ Max. Peak One Cycle Non-Repetitive Surge Current	250	A	10ms Sine pulse, rated $V_{RRM}$ applied
	300		10ms Sine pulse, no voltage reapplied
$I^2t$ Max. $I^2t$ for fusing	316	$A^2s$	10ms Sine pulse, rated $V_{RRM}$ applied
	442		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	4420	$A^2\sqrt{s}$	$t=0.1$ to 10ms, no voltage reapplied

## Electrical Specifications

Parameters	20ETS..FP	Units	Conditions
$V_{FM}$ Max. Forward Voltage Drop	1.1	V	@ 20A, $T_J = 25^\circ\text{C}$
$r_t$ Forward slope resistance	10.4	mΩ	$T_J = 150^\circ\text{C}$
$V_{F(TO)}$ Threshold voltage	0.85	V	
$I_{RM}$ Max. Reverse Leakage Current	0.1	mA	$T_J = 25^\circ\text{C}$
	1.0		$T_J = 150^\circ\text{C}$

$V_R = \text{rated } V_{RRM}$

## Thermal-Mechanical Specifications

Parameters	20ETS..FP	Units	Conditions
$T_J$ Max. Junction Temperature Range	-40 to 150	°C	
$T_{stg}$ Max. Storage Temperature Range	-40 to 150	°C	
$R_{thJC}$ Max. Thermal Resistance Junction to Case	1.5	°C/W	DC operation
$R_{thJA}$ Max. Thermal Resistance Junction to Ambient	62	°C/W	
$R_{thCS}$ Typ. Thermal Resistance Case to Heatsink	1.5	°C/W	Mounting surface, smooth and greased
wt Approximate Weight	2 (0.07)	g (oz.)	
T Mounting Torque	Min. 6 (5)	Kg-cm (lbf-in)	
	Max. 12 (10)		
Case Style	TO-220FULLPAK		(94/V0)

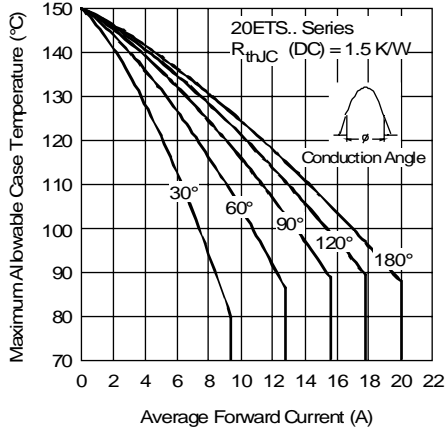


Fig. 1 - Current Rating Characteristics

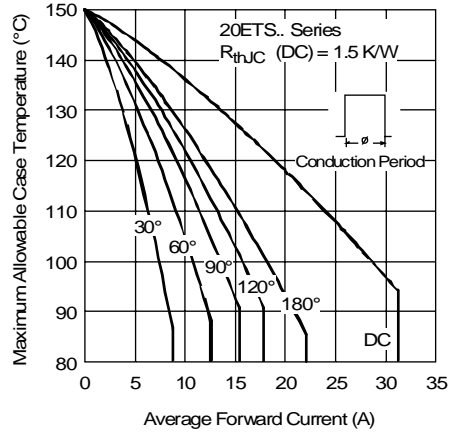


Fig. 2 - Current Rating Characteristics

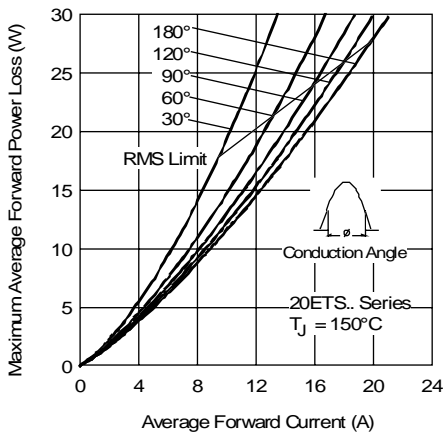


Fig. 3 - Forward Power Loss Characteristics

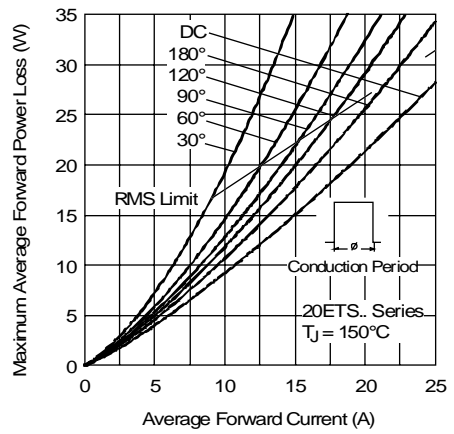


Fig. 4 - Forward Power Loss Characteristics

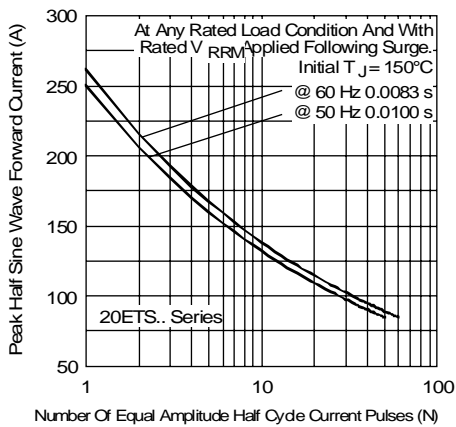


Fig. 5 - Maximum Non-Replicative Surge Current

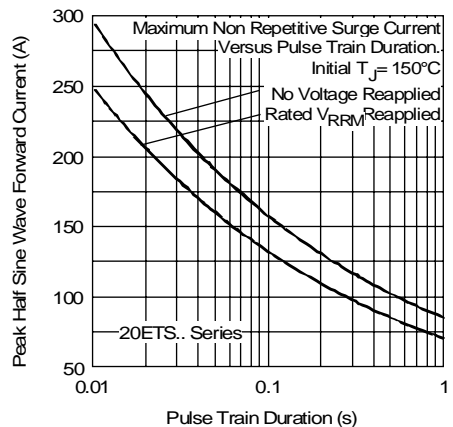


Fig. 6 - Maximum Non-Replicative Surge Current

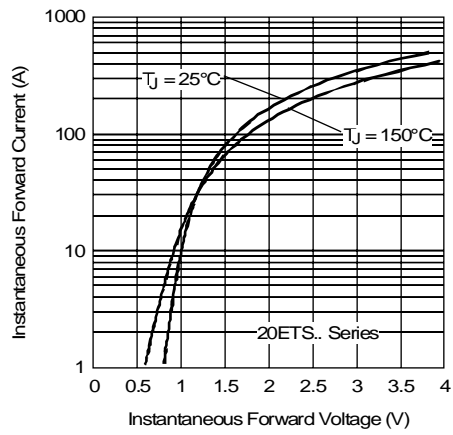


Fig.7-Forward Voltage Drop Characteristics

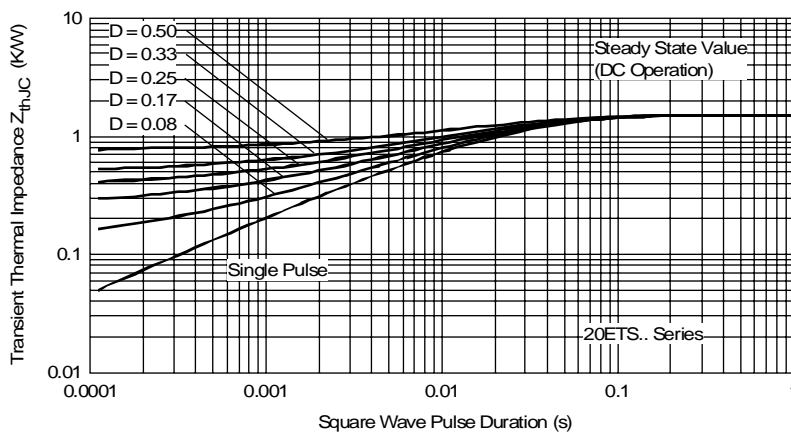
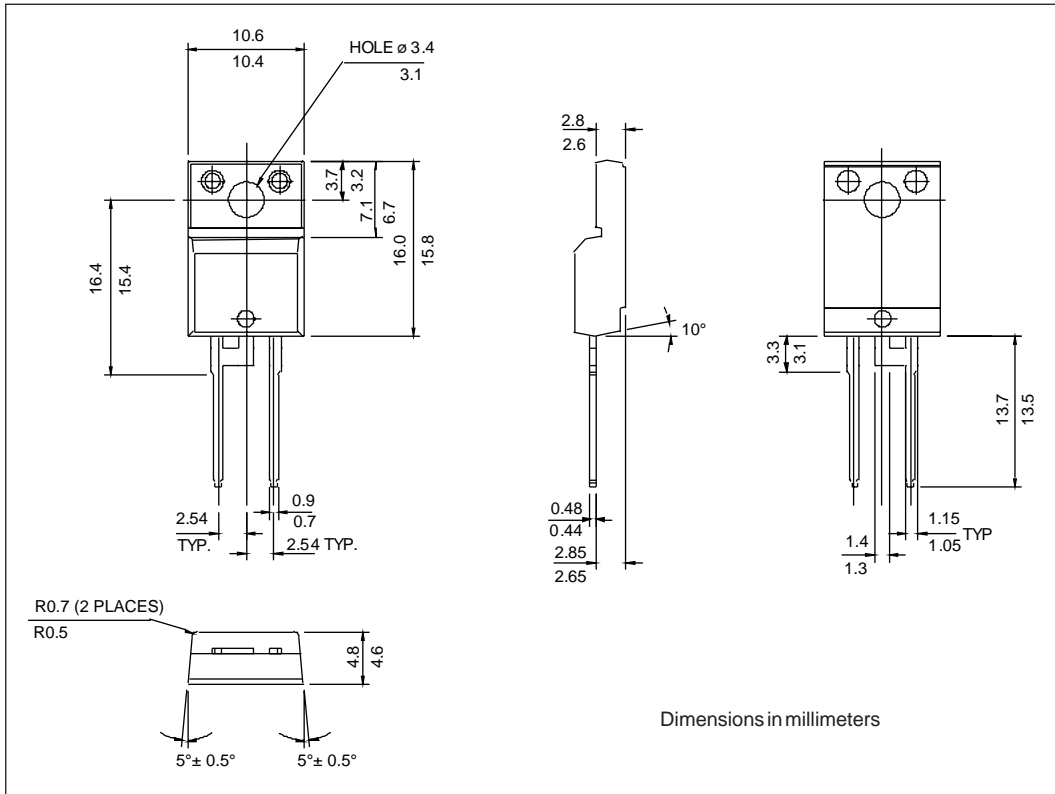


Fig. 8 - Thermal Impedance  $Z_{thjC}$  Characteristics

Outline Table



Ordering Information Table

Device Code					
20	E	T	S	16	FP
①	②	③	④	⑤	⑥

<b>1</b>	- Current Rating
<b>2</b>	- Circuit Configuration: E = Single Diode
<b>3</b>	- Package: T = TO-220AC
<b>4</b>	- Type of Silicon: S = Standard Recovery Rectifier
<b>5</b>	- Voltage code: Code x 100 = $V_{RRM}$
<b>6</b>	- TO-220 FULLPAK

08 = 800V
12 = 1200V
16 = 1600V

CATHODE ANODE

International  
**IOR** Rectifier

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Data and specifications subject to change without notice.